

### MPSA77

## **PNP Darlington Transistor**

- This device is designed for applications requiring extremely high current gain at currents to 800mA.
- Sourced from process 61.



1. Emitter 2. Base 3. Collector

### **Absolute Maximum Ratings \*** T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CES</sub>	Collector-Emitter Voltage	-60	V
V <sub>CBO</sub>	Collector-Base Voltage	-60	V
V <sub>EBO</sub>	Emitter-Base Voltage	-10	V
I <sub>C</sub>	Collector Current - Continuous	-1.2	А
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range	-55 ~ +150	°C

<sup>\*</sup> These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

- These ratings are based on a maximum junction temperature of 150 degrees C.
   These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

### Electrical Characteristics T<sub>a</sub>=25°C unless otherwise noted

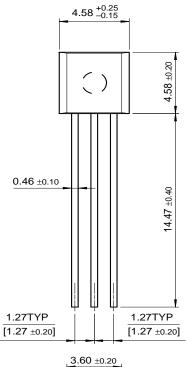
Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Chara	cteristics		·		
V <sub>(BR)CES</sub>	Collector-Emitter Breakdown Voltage	$I_C = -100\mu A, I_B = 0$	-60		V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = -30V, I <sub>E</sub> = 0		-100	nA
I <sub>EBO</sub>	Emitter Cutoff Current	$V_{EB} = -10V, I_C = 0$		-100	nA
On Chara	cteristics *				
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = -10mA, V <sub>CE</sub> = -5.0V I <sub>C</sub> = -100mA, V <sub>CE</sub> = -5.0V	10,000 10,000		
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -100mA, I <sub>B</sub> = -0.1mA		-1.5	V
V <sub>BE</sub> (on)	Base-Emitter On Voltage	$I_C = -100 \text{mA}, V_{CE} = -5.0 \text{mA}$		-2.0	V
Small Sign	nal Characteristics *	·	<u> </u>		
f <sub>T</sub>	Current Gain Dandwidth Product	I <sub>C</sub> = -10mA, V <sub>CE</sub> = -5.0V f = 100MHz	100		MHz
Pulse Test: Pu	llse Width ≤ 300μs, Duty Cycle ≤ 2.0%	1	1		

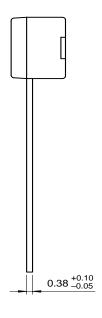
### Thermal Characteristics T<sub>a</sub>=25°C unless otherwise noted

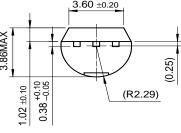
Symbol	Parameter	Max.	Units
P <sub>D</sub>	Total Device Dissipation	625	mW
	Derate above 25°C	5.0	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W

# **Package Dimensions**

TO-92







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Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
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### MPSA77

PNP Darlington Transistor

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#### **Features**

- This device is designed for applications requiring extremely high current gain at currents to 800mA.
- Sourced from process 61.

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Product status/pricing/packaging

BUY

Product	Product status	Pb-free Status	Pricing*	Package type	Leads	Packing method	Package Marking Convention**
MPSA77	Full Production	Full Production	\$0.056	<u>TO-92</u>	3	BULK	Line 1: <b>\$Y</b> (Fairchild logo) & <b>Z</b> (Asm. Plant Code) & <b>3</b> (3-Digit Date Code) Line 2: MPS Line 3: A77
MPSA77_D26Z	Full Production	Full Production	N/A	TO-92	3	TAPE REEL	Line 1: <b>\$Y</b> (Fairchild logo) & <b>Z</b> (Asm. Plant Code) & <b>3</b> (3-Digit Date Code) Line 2: MPS Line 3: A77
MPSA77_D74Z	Full Production	Full Production	N/A	TO-92	3	АММО	Line 1: <b>\$Y</b> (Fairchild logo) & <b>Z</b> (Asm. Plant Code) & <b>3</b> (3-Digit Date Code) Line 2: MPS Line 3: A77
MPSA77_D75Z	Full Production		N/A	<u>TO-92</u>	3		Line 1: <b>\$Y</b> (Fairchild logo) & <b>Z</b> (Asm. Plant Code)

	Full Production		&3 (3-Digit Date Code) Line 2: MPS Line 3: A77	
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<sup>\*</sup> Fairchild 1,000 piece Budgetary Pricing

\*\* A sample button will appear if the part is available through Fairchild's on-line samples program. If there is no sample button, please contact a Fairchild distributor to obtain samples



Indicates product with Pb-free second-level interconnect. For more information click here.

Package marking information for product MPSA77 is available. Click here for more information .

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Product
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